DUAL OPERATIONAL AMPLIFIER

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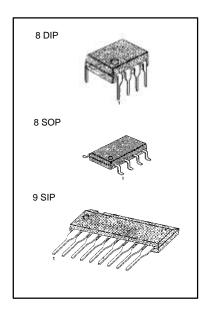
The LM1458 series are dual general purpose operational amplifiers, having short circuits protected and require no external components for frequency compensation.

High common mode voltage range and absence of "latch up" make the LM1458 ideal for use as voltage followers.

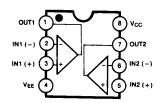
The high gain and wide range of operating voltage provides superior performance in integrator, summing amplifier and general feedback applications.

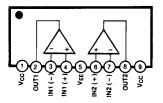
FEATURES

- Internal frequency compensation
- Short circuit protection
- Large common mode and differential voltage range
- No latch up
- Low power consumption



BLOCK DIAGRAM





ORDERING INFORMATION

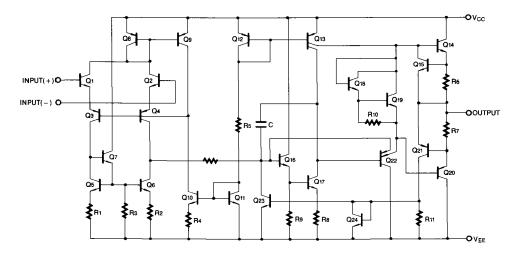
Device	Package	Operating Temperature
LM1458CN (KA1458)	8 DIP	
LM1458N (KA1458A)	0 DIF	
KA1458S	9 SIP	0 ~ + 70°C
KA1458AS	9 OIF	0~+700
LM1458CM (KA1458D)	8 SOP	
LM1458M (KA1458AD)	0 30F	
KA1458I	8 DIP	
KA1458AI	0 DIF	
KA1458IS	9 SIP	-25 ~ + 85°C
KA1458AIS	9 SIP	-25 ~ + 85°C
KA1458ID	8 SOP	
KA1458AID	0 30F	



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Rev. C

SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Characteristic	Symbol	Value	Unit
Power Supply Voltage	Vcc	±18	V
Input Differential Voltage	V _{I(DIFF)}	30	V
Input Voltage	VI	±15	V
Operating Temperature Range LM1458I/AI	T _{OPR}	- 25 ~ + 85	°C
LM1458/A		0 ~ + 70	°C
Storage Temperature Range	T _{STG}	- 65 ~ + 150	°C



ELECTRICAL CHARACTERISTICS

(V_{CC} = + 15V, V_{EE} = - 15V, T_A = 25 $^\circ C$ unless otherwise specified)

Characteristic	Ourseland	Test Conditions	LM1458A/AI			L	M145	1114		
Characteristic	Symbol	Test Conditions	Min	Тур	Max	Min	Тур	Max	Unit	
Input Offset Voltage	V _{IO}	R _S ≤10KΩ		2.0	6.0		2.0	10	mV	
Input Offset Current	I _{IO}			20	200		20	300	nA	
Input Bias Current	I _{BIAS}			80	500		80	700	nA	
Large Signal Voltage Gain	Gv	$V_{O(P-P)} = \pm 10V, R_L \ge 2.0 K\Omega$	20	200		20	200		V/mV	
Input Voltage Range	V _{I(R)}		± 12	± 13		± 11	± 13		V	
Input Resistance	Rı		0.3	1.0		0.3	1.0		MΩ	
Common Mode Rejection Ratio	CMRR		70	90		60	90		dB	
Power Supply Rejection Ratio	PSRR		77	90		77	90		dB	
Supply Current (Both Amplifier)	Icc			2.3			2.3	8.0	mA	
Output Voltage Swing	V _{O(P.P)}	R _S ≤10KΩ	± 12	± 14	5.6	± 11	±14		v	
		R _S ≤10KΩ	± 10	± 13		± 9	± 13		v	
Output Short Circuit Current	I _{SC}			20			20		mA	
Power Consumption	Pc	$V_{O} = 0V$		70	170		70	240	mW	
Transient Response (Unity Gain)										
Rise Time	t _{RES}	$V_{I} = 20mV, R_{L} \ge 2K\Omega, C_{L} \le 100pF$		0.3			0.3		μs	
Overshoot	OS	$V_1 = 20mV, R_L \ge 2K\Omega, C_L \le 100pF$		15			15		%	
Slew Rate	SR	$V_1 = 10V, R_L \ge 2K\Omega, C_L \le 100pF$		0.5			0.5		V/µs	

ELECTRICAL CHARACTERISTICS

(V_{CC}= +15V, V_{EE} = -15V, NOTE 1, unless otherwise specified)

Characteristic	Symbol Test Conditions	LM1458A/AI			LM1458/I			l lmit		
Characteristic	Symbol	or rest conditions	Min	Тур	Max	Min	Тур	Max	Unit	
Input Offset Voltage	VIO	R _s ≤10KΩ			7.5			12	mV	
Input Offset Current	I _{IO}				300			400	nA	
Input Bias Current	IBIAS				800			1000	nA	
Large Signal Voltage Gain	Gv	$V_{O(P-P)} = \pm 10V, R_L \le 2.0 K\Omega$	15			15			V/mV	
Common Mode Rejection Ratio	CMRR	R _s ≥10KΩ	70	90		70	90		dB	
Power Supply Rejection Ratio	PSRR	R _S ≥10KΩ	77	90		77	90		dB	
Output Voltage Swing	V	R _L = 10KΩ	± 12	± 14		± 11	± 14		V	
	V _{O(P.P)}	$R_L = 2K\Omega$	± 10	± 13		± 9	± 13		v	
Input Voltage Range	V _{I(R)}		± 12			± 12			V	

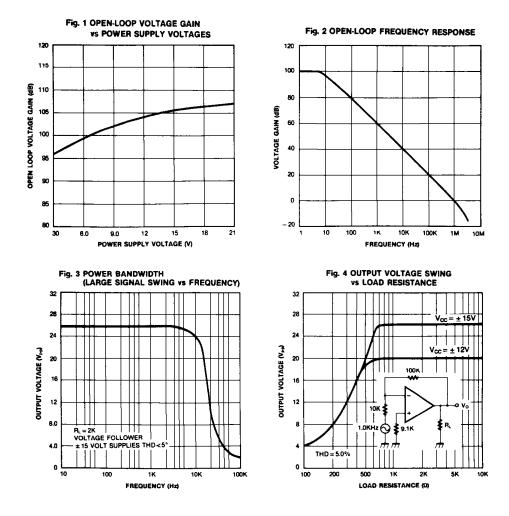
NOTE 1

LM1458/A: 0 °C ≤T_A≤70 °C LM1458I/AI: -25 °C ≤T_A≤+85 °C



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TYPICAL PERFORMANCE CHARACTERISTICS





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